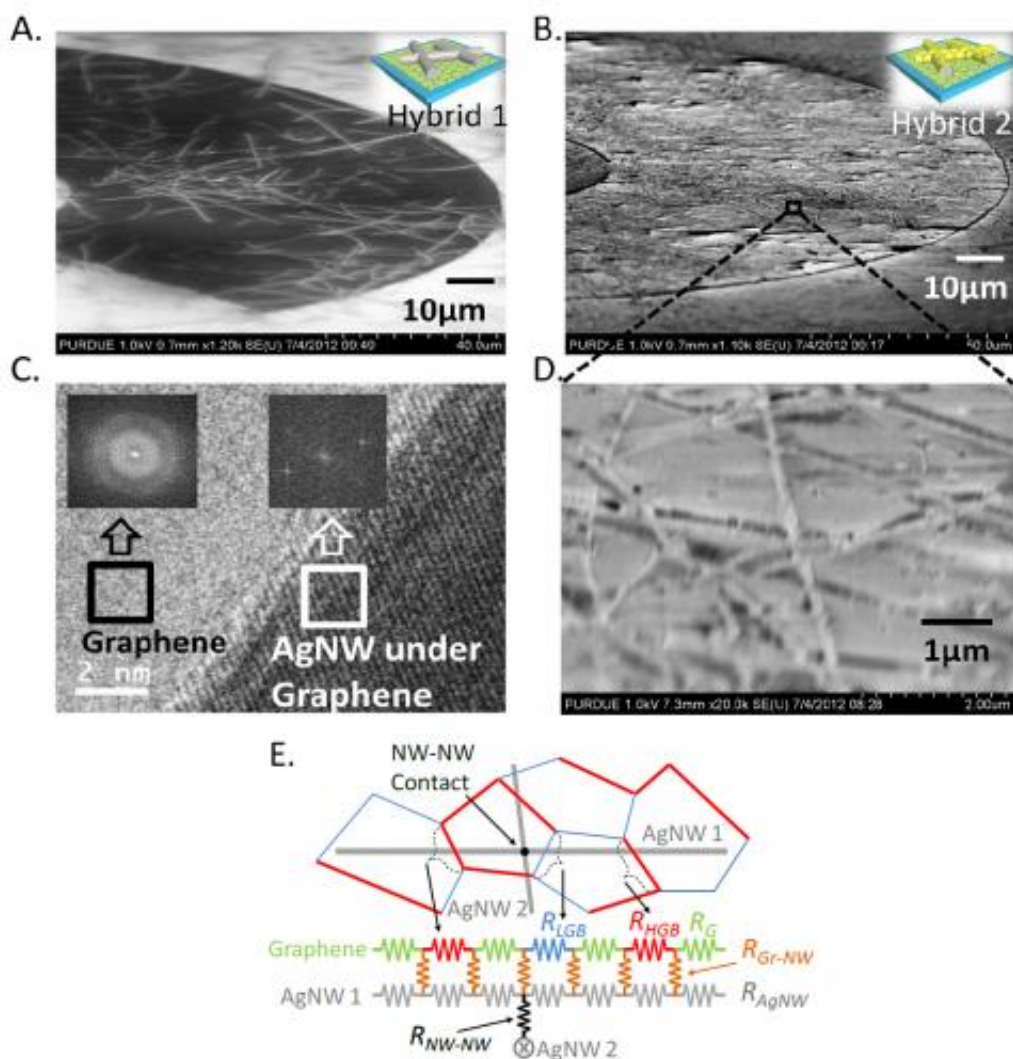


# Transparent electrode innovation could bring flexible solar cells, transistors, displays

May 22 2013, by Emil Venere



These electron microscope images show a new material for transparent electrodes that might find uses in solar cells, flexible displays for computers and consumer electronics, and future "optoelectronic" circuits for sensors and information processing. The electrodes are made of silver nanowires covered

with a material called graphene. At bottom is a model depicting the "co-percolating" network of graphene and silver nanowires. Credit: Birck Nanotechnology Center, Purdue University

(Phys.org) —Researchers have created a new type of transparent electrode that might find uses in solar cells, flexible displays for computers and consumer electronics and future "optoelectronic" circuits for sensors and information processing.

The electrode is made of silver [nanowires](#) covered with a material called graphene, an extremely thin layer of carbon. The hybrid material shows promise as a possible replacement for [indium tin oxide](#), or ITO, used in transparent electrodes for touch-screen monitors, cell-phone displays and flat-screen televisions. Industry is seeking alternatives to ITO because of drawbacks: It is relatively expensive due to limited abundance of indium, and it is inflexible and degrades over time, becoming brittle and hindering performance.

"If you try to bend ITO it cracks and then stops functioning properly," said Purdue University doctoral student Suprem Das.

The hybrid material could represent a step toward innovations, including flexible [solar cells](#) and color monitors, flexible "heads-up" displays in car windshields and information displays on eyeglasses and visors.

"The key innovation is a material that is transparent, yet electrically conductive and flexible," said David Janes, a professor of electrical and computer engineering.

Research findings were detailed in a paper appearing online in April in the journal *Advanced Functional Materials*. The paper is available online

at <http://onlinelibrary.wiley.com/doi/10.1002/adfm.201300124/full>. It was authored by Das; visiting student Ruiyi Chen; graduate students Changwook Jeong and Mohammad Ryyan Khan; Janes and Muhammad A. Alam, a Purdue professor of electrical and computer engineering.

The hybrid concept was proposed in earlier publications by Purdue researchers, including a 2011 paper in the journal *Nano Letters*. The concept represents a general approach that could apply to many other materials, said Alam, who co-authored the *Nano Letters* paper.

"This is a beautiful illustration of how theory enables a fundamental new way to engineer material at the nanoscale and tailor its properties," he said.

Such hybrid structures could enable researchers to overcome the "electron-transport bottleneck" of extremely thin films, referred to as two-dimensional [materials](#).

Combining graphene and silver nanowires in a hybrid material overcomes drawbacks of each material individually: the graphene and nanowires conduct electricity with too much resistance to be practical for transparent electrodes. Sheets of graphene are made of individual segments called grains, and resistance increases at the boundaries between these grains. Silver nanowires, on the other hand, have high resistance because they are randomly oriented like a jumble of toothpicks facing in different directions. This random orientation makes for poor contact between nanowires, resulting in high resistance.

"So neither is good for conducting electricity, but when you combine them in a hybrid structure, they are," Janes said.

The graphene is draped over the silver nanowires.

"It's like putting a sheet of cellophane over a bowl of noodles," Janes said. "The graphene wraps around the silver nanowires and stretches around them."

Findings show the material has a low "sheet resistance," or the electrical resistance in very thin layers of material, which is measured in units called "squares." At 22 ohms per square, it is five times better than ITO, which has a sheet resistance of 100 ohms per square.

Moreover, the hybrid structure was found to have little resistance change when bent, whereas ITO shows dramatic increases in resistance when bent.

"The generality of the theoretical concept underlying this experimental demonstration – namely 'percolation-doping'—suggests that it is likely to apply to a broad range of other 2-D nanocrystalline material, including graphene," Alam said.

A patent application has been filed by Purdue's Office of Technology Commercialization.

**More information:** Co-Percolating Graphene-Wrapped Silver Nanowire Network for High Performance, Highly Stable, Transparent Conducting Electrodes, *Advanced Functional Materials*, 2013.

## **Abstract**

Transparent conducting electrodes (TCEs) require high transparency and low sheet resistance for applications in photovoltaics, photodetectors, flat panel displays, touch screen devices and imagers. Indium tin oxide (ITO), or other transparent conductive oxides, have typically been used, and provide a baseline sheet resistance (RS) vs. transparency (T) relationship. However, ITO is relatively expensive (due to limited abundance of Indium), brittle, unstable, and inflexible; moreover, ITO

transparency drops rapidly for wavelengths above 1,000 nm. Motivated by a need for transparent conductors with comparable (or better)  $R_{\text{Sat}}$  at a given  $T$ , as well as flexible structures, several alternative material systems have been investigated. Single-layer graphene (SLG) or few-layer graphene provide sufficiently high transparency ( $\approx 97\%$  per layer) to be a potential replacement for ITO. However, large-area synthesis approaches, including chemical vapor deposition (CVD), typically yield films with relatively high sheet resistance due to small grain sizes and high-resistance grain boundaries (HGBs). In this paper, we report a hybrid structure employing a CVD SLG film and a network of silver nanowires (AgNWs):  $RS$  as low as  $22 \Omega/\square$  (stabilized to  $13 \Omega/\square$  after 4 months) have been observed at high transparency ( $88\%$  at  $\lambda = 550 \text{ nm}$ ) in hybrid structures employing relatively low-cost commercial graphene with a starting  $RS$  of  $770 \Omega/\square$ . This sheet resistance is superior to typical reported values for ITO, comparable to the best reported TCEs employing graphene and/or random nanowire networks, and the film properties exhibit impressive stability under mechanical pressure, mechanical bending and over time. The design is inspired by the theory of a co-percolating network where conduction bottlenecks of a 2D film (e.g., SLG, MoS<sub>2</sub>) are circumvented by a 1D network (e.g., AgNWs, CNTs) and vice versa. The development of these high-performance hybrid structures provides a route towards robust, scalable and low-cost approaches for realizing high-performance TCE.

Provided by Purdue University

Citation: Transparent electrode innovation could bring flexible solar cells, transistors, displays (2013, May 22) retrieved 8 May 2024 from <https://phys.org/news/2013-05-transparent-electrode-flexible-solar-cells.html>

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